

OPA1688, OPA1689 SBOS724 – SEPTEMBER 2015

OPA168x

Technical

Documents

Sample &

Buy

SoundPlus 36-V, Single-Supply, 10-MHz, Rail-to-Rail Output Operational Amplifiers

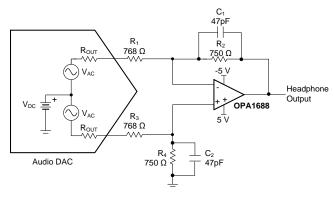
1 Features

- THD+N, 50 mW, 32 $\Omega,$ 1 kHz, –109 dB
- Wide Supply Range:
 - $\,$ 4.5 V to 36 V, ±2.25 V to ±18 V $\,$
- Low Offset Voltage: ±0.25 mV
- Low Offset Drift: ±0.5 µV/°C
- Gain Bandwidth: 10 MHz
- Low Input Bias Current: ±10 pA
- Low Quiescent Current: 1.6 mA per Amplifier
- Low Noise: 8 nV/√Hz
- EMI- and RFI-Filtered Inputs
- Input Range Includes Negative Supply
- Input Range Operates to Positive Supply
- Rail-to-Rail Output
- High Common-Mode Rejection: 120 dB
 - Industry-Standard Packages:
 - SOIC-8 and SOIC-14
- microPackages:
 - Dual in WSON-8, Quad in VQFN-16

2 Applications

- Headphone Driver
- Analog and Digital Mixers
- Audio Effects Processors
- Transducer Amplifiers
- Musical Instruments
- A/V Receivers
- DVD and Blu-Ray[™] Players
- Car Audio Systems

Headphone Amplifier Circuit Configuration



3 Description

Tools &

Software

The OPA1688 and OPA1689 are a family of single-supply, SoundPlus™ 36-V. low-noise operational amplifiers capable of operating on supplies ranging from 4.5 V (±2.25 V) to 36 V (±18 V). This latest addition of high-voltage audio operational amplifiers, in conjunction with the OPA16xx devices provide a family of bandwidth, noise, and power options to meet the needs of a wide variety of applications. The OPA168x are available in micropackages, and offer low offset, drift, and quiescent current. These devices also offer wide bandwidth, fast slew rate, and high output current drive capability. The dual and guad versions all have identical specifications for maximum design flexibility.

Support &

Community

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Unlike most op amps that are specified at only one supply voltage, the OPA168x family is specified from 4.5 V to 36 V. Input signals beyond the supply rails do not cause phase reversal. The input can operate 100 mV below the negative rail and within 2 V of the top rail during normal operation. Note that these devices can operate with full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail.

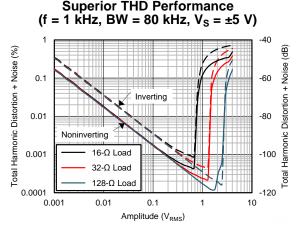
The OPA168x series of op amps are specified from -40° C to 85° C.

PART NUMBER	PACKAGE	BODY SIZE (NOM)			
OPA1688	SOIC (8)	4.90 mm × 3.91 mm			
OPATOOO	WSON (8)	3.00 mm × 3.00 mm			
OPA1689 ⁽²⁾	SOIC (14)	8.65 mm × 3.91 mm			
UPA1009.7	VQFN (16)	3.50 mm × 3.50 mm			

Device Information⁽¹⁾

(1) For all available packages, see the orderable addendum at the end of the datasheet.

(2) Product-preview device.



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4 Revision History

DATE	REVISION	NOTES
September 2015	*	Initial release.



5 Device Comparison Table

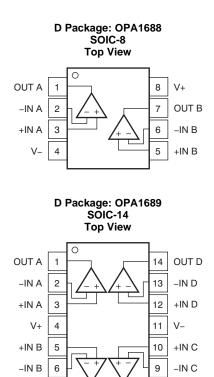
DEVICE ⁽¹⁾	PACKAGE
OPA1688 (dual)	SOIC-8, WSON-8
OPA1689 (quad)	SOIC-14, VQFN-16

(1) The OPA1688 SOIC-8 and WSON-8 packages are production data. The OPA1689 SOIC-14 and VQFN-16 packages are product preview.

6 Device Family Comparison Table

DEVICE	QUIESCENT CURRENT (I _Q)	GAIN BANDWIDTH PRODUCT (GBP)	VOLTAGE NOISE DENSITY (e _n)
OPA168x	1650 µA	10 MHz	8 nV/√ Hz
OPA165x	2000 µA	18 MHz	4.5 nV/√Hz
OPA166x	1500 μA	22 MHz	3.3 nV/√ Hz

7 Pin Configuration and Functions

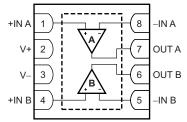


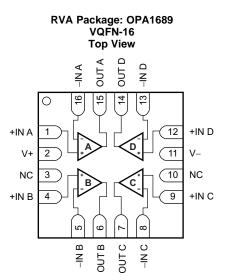
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OUT C



Top View





OUT B

7

Pin Functions: OPA1688

PIN				
	OP/	1688		
NAME	D (SOIC)	DRG (WSON)	I/O	DESCRIPTION
+IN A	3	1	I	Noninverting input, channel A
+IN B	5	4	I	Noninverting input, channel B
–IN A	2	8	I	Inverting input, channel A
–IN B	6	5	I	Inverting input, channel B
OUT A	1	7	0	Output, channel A
OUT B	7	6	0	Output, channel B
V+	8	2	—	Positive (highest) power supply
V–	4	3	—	Negative (lowest) power supply

Pin Functions: OPA1689

	PIN			
	OPA	1689		
NAME	D	RVA	I/O	DESCRIPTION
+IN A	3	1	I	Noninverting input, channel A
+IN B	5	4	I	Noninverting input, channel B
+IN C	10	9	I	Noninverting input, channel C
+IN D	12	12	I	Noninverting input, channel D
–IN A	2	16	I	Inverting input, channel A
–IN B	6	5	I	Inverting input, channel B
–IN C	9	8	I	Inverting input, channel C
–IN D	13	13	I	Inverting input, channel D
OUT A	1	15	0	Output, channel A
OUT B	7	6	0	Output, channel B
OUT C	8	7	0	Output, channel C
OUT D	14	14	0	Output, channel D
V+	4	2	_	Positive (highest) power supply
V–	11	11	—	Negative (lowest) power supply
NC	_	3, 10	—	No connection



8 Specifications

8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
Supply voltage, V _S			±20 (40, single supply)	V	
	Voltage ⁽²⁾	Common-mode	(V–) – 0.5	(V+) + 0.5	V
Signal input pins	voitage	Differential ⁽³⁾		±0.5	V
	Current			±10	mA
Output short circuit ⁽⁴⁾			Continuous		
	Temperature range)	-55	150	°C
Temperature	Junction temperatu	ire		150	°C
	Storage, T _{stg}		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Transient conditions that exceed these voltage ratings should be current limited to 10 mA or less.

(3) See the *Electrical Overstress* section for more information.

(4) Short-circuit to ground, one amplifier per package.

8.2 ESD Ratings

			VALUE	UNIT
	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	v

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM MAX	UNIT
Supply voltage (V+ – V–)	4.5 (±2.25)	36 (±18)	V
Specified temperature	-40	85	°C

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8.4 Thermal Information: OPA1688

		OPA	OPA1688		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DRG (WSON)	UNIT	
		8 PINS	8 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	116.1	63.2	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	69.8	63.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	56.6	36.5	°C/W	
Ψ _{JT}	Junction-to-top characterization parameter	22.5	1.4	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	56.1	36.6	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	6.3	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

8.5 Thermal Information: OPA1689

		OPA		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	RVA (VQFN)	UNIT
		14 PINS	16 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	82.7	TBD	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	42.3	TBD	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.3	TBD	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	8.9	TBD	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	37	TBD	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	TBD	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



8.6 Electrical Characteristics

At $T_A = 25^{\circ}$ C, $V_S = \pm 2.25$ V to ± 18 V, $V_{CM} = V_{OUT} = V_S / 2$, and $R_L = 10$ k Ω connected to $V_S / 2$, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
AUDIO PE	RFORMANCE	·				
				0.00005%		
		$G = 1, f = 1 \text{ kHz}, V_O = 3.5 V_{RMS}, R_L = 2 \text{ k}\Omega$		-126		dB
				0.000051%		
	Total harmonic distortion	G = 1, f = 1 kHz, V_O = 3.5 V_{RMS} , R_L = 600 Ω		-126		dB
				0.000153%		
THD+N	+ noise	G = 1, f = 1 kHz, P_0 = 10 mW, R_L = 128 Ω		-116		dB
				0.000357%		
		G = 1, f = 1 kHz, P_0 = 10 mW, R_L = 32 Ω		-109		dB
				0.000616%		
		G = 1, f = 1 kHz, P_O = 10 mW, R_L = 16 Ω		-104		dB
FREQUEN						
GBP	Gain bandwidth product	G = 1		10		MHz
SR	Slew rate	G = 1		8		V/µs
	Full-power bandwidth ⁽¹⁾	$V_0 = 1 V_{PP}$		1.3		MHz
	Overload recovery time	$V_{IN} \times gain > V_S$		200		ns
	Channel separation					110
	(dual)	f = 1 kHz		-120		dB
ts	Settling time	To 0.1%, V _S = ±18 V, G = 1, 10-V step		3		μs
NOISE			1			
En	Input voltage noise	f = 0.1 Hz to 10 Hz		2.5		μV_{PP}
	Input voltage noise	f = 100 Hz		14		
e _n	en density ⁽²⁾	f = 1 kHz		8		nV/√Hz
	Input current noise	£ 4 141-		1.0		fA/√Hz
i _n	density	f = 1 kHz		1.8		IA/ \IEZ
OFFSET V	OLTAGE					
Vos	Input offset voltage	$T_A = 25^{\circ}C$		±0.25	±1.5	mV
VOS	input onset voltage	$T_A = -40^{\circ}C$ to $85^{\circ}C$			±1.6	IIIV
dV _{OS} /dT	V _{OS} over temperature ⁽²⁾	$T_A = -40^{\circ}C$ to $85^{\circ}C$		±0.5	±2	μV/°C
PSRR	Power-supply rejection	$T_A = -40^{\circ}C$ to $85^{\circ}C$		±1	±2.5	μV/V
-	ratio					•
	Channel separation, dc	At dc		0.1		μV/V
INPUT BIA	AS CURRENT	T 0700				
I _B	Input bias current	T _A = 25°C		±10	±20	pA
	·	$T_A = -40^{\circ}C$ to $85^{\circ}C$			±1.5	nA
los	Input offset current	$T_A = 25^{\circ}C$		±3	±7	pА
	•	$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$			±250	pА
INPUT VO	LTAGE RANGE	Ι				
V _{CM}	Common-mode voltage range ⁽³⁾		(V–) – 0.1 V		(V+) – 2 V	V
	Common-mode rejection	$V_{S} = \pm 2.25 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) - 2 \text{ V},$ $T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$	90	104		
CMRR Common-mode rejection ratio		$V_{\rm S} = \pm 18 \text{ V}, (V-) - 0.1 \text{ V} < V_{\rm CM} < (V+) - 2 \text{ V},$ $T_{\rm A} = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ 104		120		dB
	PEDANCE	· · · · · · · · · · · · · · · · · · ·				
	Differential			100 7		MΩ pF
	Common-mode			6 1.5		10 ¹² Ω pF

(1) Full-power bandwidth = SR / $(2\pi \times V_P)$, where SR = slew rate.

Specified by design and characterization. Common-mode range can extend to the top rail with reduced performance. (2) (3)



Electrical Characteristics (continued)

At $T_A = 25^{\circ}$ C, $V_S = \pm 2.25$ V to ± 18 V, $V_{CM} = V_{OUT} = V_S / 2$, and $R_L = 10$ k Ω connected to $V_S / 2$, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OPEN-LC	OOP GAIN						
		$ (V-) + 0.35 \ V < V_O < (V+) - 0.35 \ V, \ R_L = 10 \ k\Omega, \\ T_A = -40^\circ C \ to \ 85^\circ C $	108	130		dB	
A _{OL}	Open-loop voltage gain	$ (V-) + 0.5 V < V_O < (V+) - 0.5 V, R_L = 2 k\Omega, \\ T_A = -40^\circ C \ to \ 85^\circ C $		118		uв	
OUTPUT							
		$I_L = \pm 1 \text{ mA}$	(V–) + 0.1 V		(V+) – 0.1 V		
Vo	Voltage output swing from rail	$V_{\rm S} = 36 \text{ V}, \text{ R}_{\rm L} = 10 \text{ k}\Omega$		70	90	mV	
	nom ran	$V_{\rm S}$ = 36 V, R _L = 2 k Ω		330	400		
Z _O	Open-loop output impedance	f = 1 MHz, I _O = 0 A		60		Ω	
I _{SC}	Short-circuit current			±75		mA	
C _{LOAD}	Capacitive load drive		See the Typ	oical Character	istics	pF	
POWER	SUPPLY						
Vs	Specified voltage range		4.5		36	V	
	Quiescent current per	$I_0 = 0 A$		1.6	1.8		
lQ	amplifier	$I_{O} = 0 \text{ A}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$				mA	
TEMPER	ATURE RANGE	·	·				
	Specified range		-40		85	°C	
	Operating range		-55		125	°C	

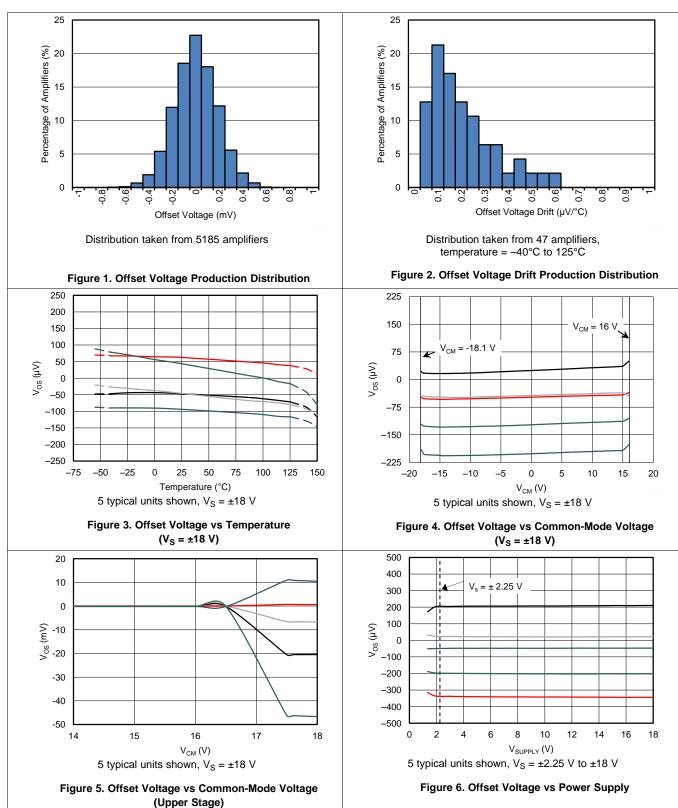


8.7 Typical Characteristics: Table of Graphs

Table 1. List of Typical Characteristics

DESCRIPTION	FIGURE
Offset Voltage Production Distribution	Figure 1
Offset Voltage Drift Distribution	Figure 2
Offset Voltage vs Temperature (V _S = ±18 V)	Figure 3
Offset Voltage vs Common-Mode Voltage (V _S = ±18 V)	Figure 4
Offset Voltage vs Common-Mode Voltage (Upper Stage)	Figure 5
Offset Voltage vs Power Supply	Figure 6
Input Bias Current vs Common-Mode Voltage	Figure 7
Input Bias Current vs Temperature	Figure 8
Output Voltage Swing vs Output Current (Maximum Supply)	Figure 9
CMRR and PSRR vs Frequency (Referred-to-Input)	Figure 10
CMRR vs Temperature	Figure 11
PSRR vs Temperature	Figure 12
0.1-Hz to 10-Hz Noise	Figure 13
Input Voltage Noise Spectral Density vs Frequency	Figure 14
THD+N Ratio vs Frequency	Figure 15
THD+N vs Output Amplitude	Figure 16
THD+N vs Frequency	Figure 17
THD+N vs Amplitude	Figure 18
Quiescent Current vs Temperature	Figure 19
Quiescent Current vs Supply Voltage	Figure 20
Open-Loop Gain and Phase vs Frequency	Figure 21
Closed-Loop Gain vs Frequency	Figure 22
Open-Loop Gain vs Temperature	Figure 23
Open-Loop Output Impedance vs Frequency	Figure 24
Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)	Figure 25, Figure 26
Positive Overload Recovery	Figure 27, Figure 28
Negative Overload Recovery	Figure 29, Figure 30
Small-Signal Step Response (10 mV, G = -1)	Figure 31
Small-Signal Step Response (10 mV, G = 1)	Figure 32
Small-Signal Step Response (100 mV, G = -1)	Figure 33
Small-Signal Step Response (100 mV, G = 1)	Figure 34
Large-Signal Step Response (10 V, G = -1)	Figure 35
Large-Signal Step Response (10 V, G = 1)	Figure 36
Large-Signal Settling Time (10-V Positive Step)	Figure 37
Large-Signal Settling Time (10-V Negative Step)	Figure 38
No Phase Reversal	Figure 39
Short-Circuit Current vs Temperature	Figure 40
Maximum Output Voltage vs Frequency	Figure 41
EMIRR vs Frequency	Figure 42
Channel Separation vs Frequency	Figure 43

8.8 Typical Characteristics V_{S} = ±18 V, V_{CM} = V_{S} / 2, R_{LOAD} = 10 k Ω connected to V_{S} / 2, and C_{L} = 100 pF, unless otherwise noted.

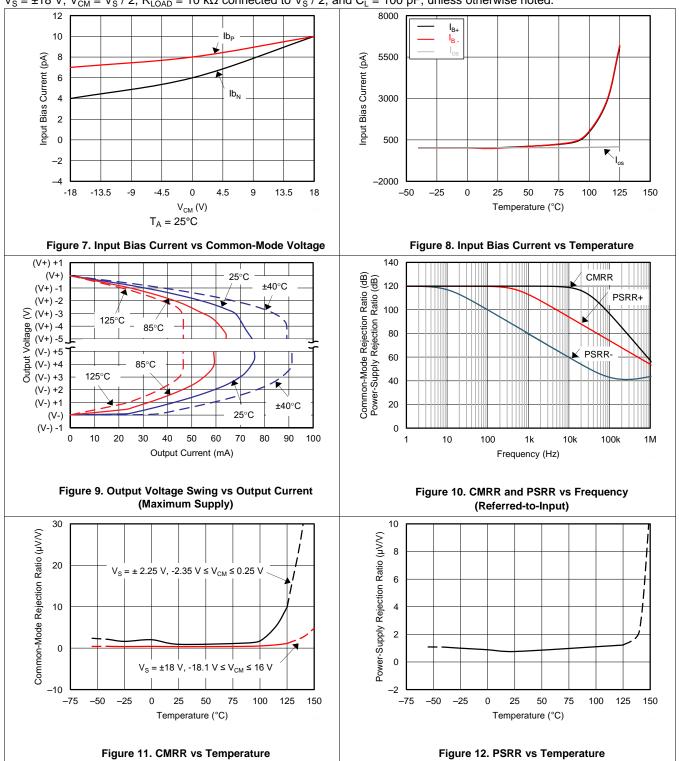




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Typical Characteristics (continued)

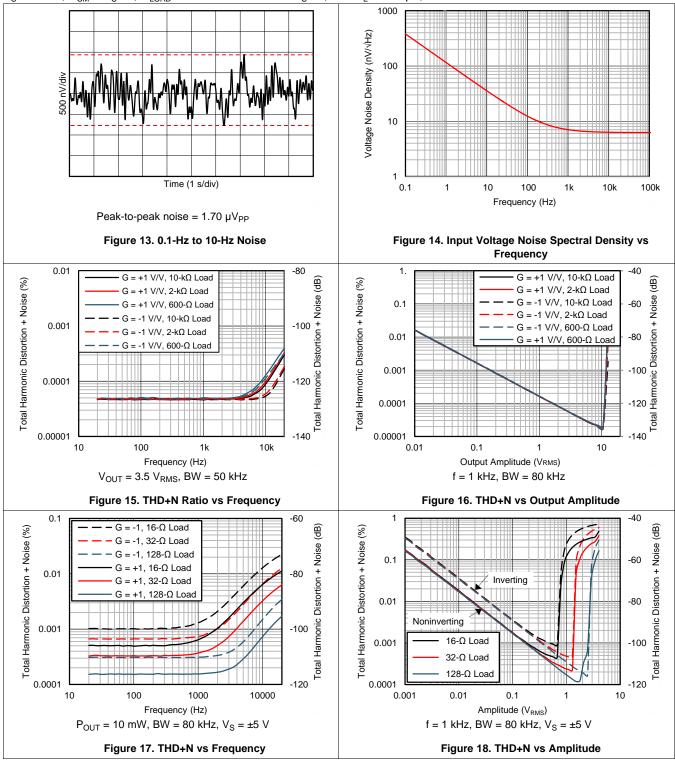


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STRUMENTS

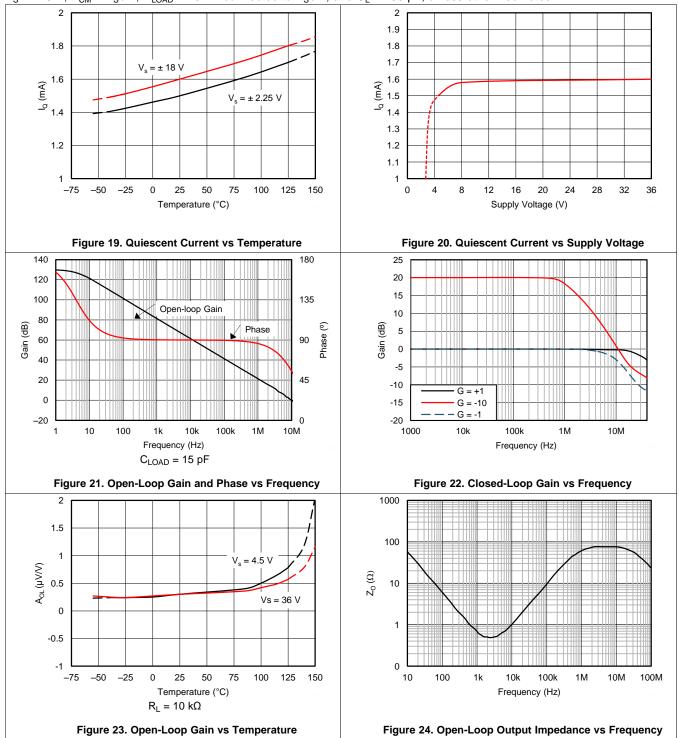
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Typical Characteristics (continued)





Typical Characteristics (continued)

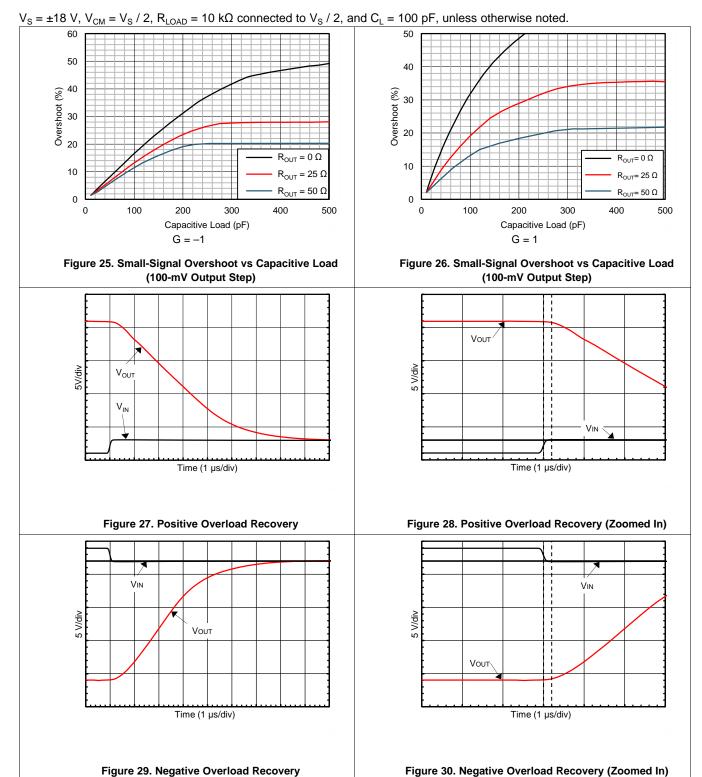


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STRUMENTS

EXAS

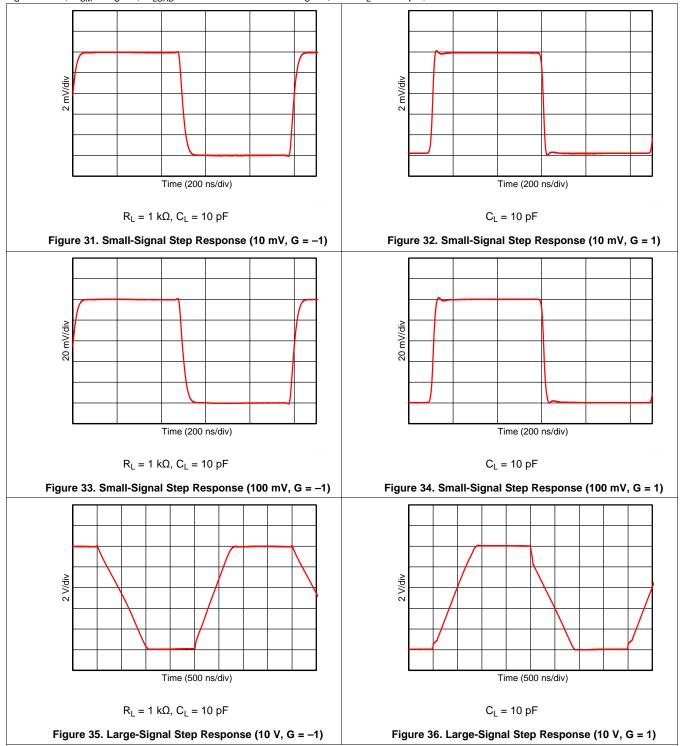
Typical Characteristics (continued)



Product Folder Links: OPA1688 OPA1689



Typical Characteristics (continued)



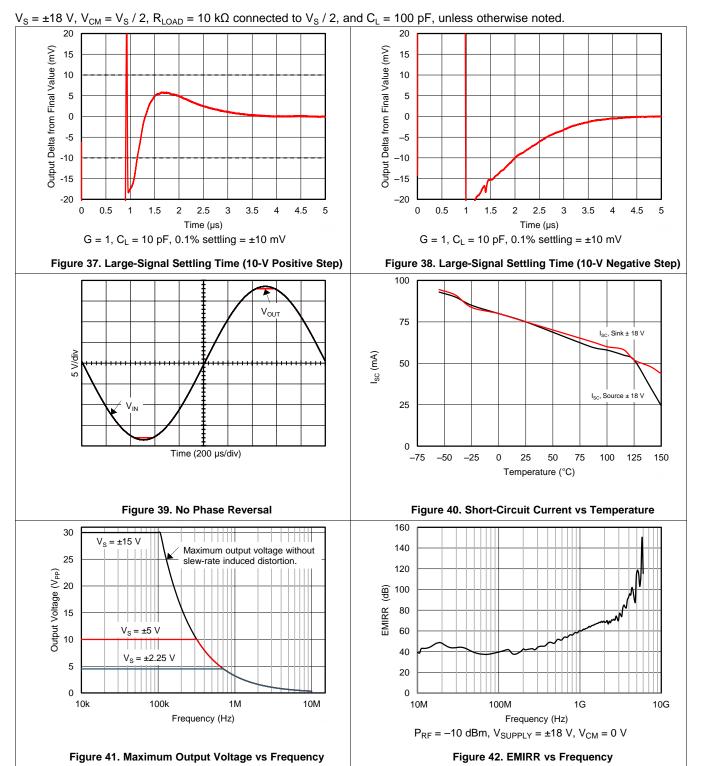
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STRUMENTS

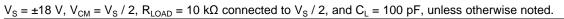
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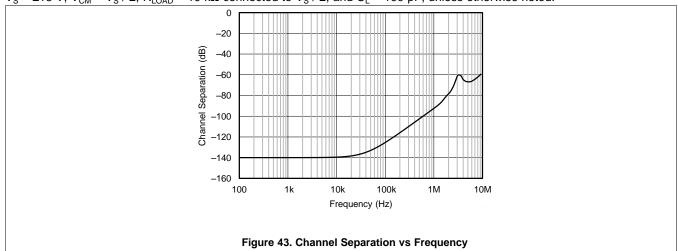
Typical Characteristics (continued)





Typical Characteristics (continued)





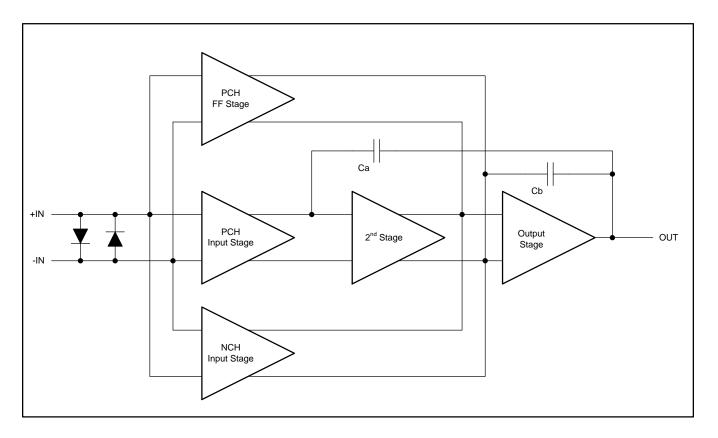
9 Detailed Description

9.1 Overview

The OPA168x family of operational amplifiers provide high overall performance, making them ideal for many general-purpose applications. The excellent offset drift of only 1.5 μ V/°C (max) provides excellent stability over the entire temperature range. In addition, the device offers very good overall performance with high CMRR, PSRR, A_{OL}, and superior THD.

The *Functional Block Diagram* section shows the simplified diagram of the OPA168x design. The design topology is a highly-optimized, three-stage amplifier with an active-feedforward gain stage.

9.2 Functional Block Diagram

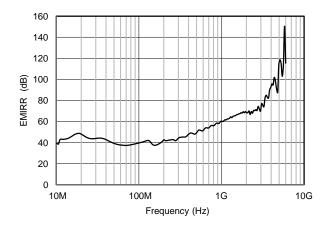




9.3 Feature Description

9.3.1 EMI Rejection

The OPA168x uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPA168x benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 44 shows the results of this testing on the OPA168x. Table 2 shows the EMIRR IN+ values for the OPA168x at particular frequencies commonly encountered in real-world applications. Applications listed in Table 2 can be centered on or operated near the particular frequency shown. Detailed information can also be found in application report SBOA128, *EMI Rejection Ratio of Operational Amplifiers*, available for download from www.ti.com.



 $P_{RF} = -10 \text{ dBm}, V_{SUPPLY} = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$

Figure 44. EMIRR Testing

FREQUENCY	APPLICATION OR ALLOCATION	EMIRR IN+
400 MHz	Mobile radio, mobile satellite, space operation, weather, radar, and ultrahigh frequency (UHF) applications	47.6 dB
900 MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, and UHF applications	58.5 dB
1.8 GHz	GSM applications, mobile personal communications, broadband, satellite, and L-band (1 GHz to 2 GHz)	68 dB
2.4 GHz	802.11b, 802.11g, 802.11n, Bluetooth [®] , mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, and S-band (2 GHz to 4 GHz)	69.2 dB
3.6 GHz	Radiolocation, aero communication and navigation, satellite, mobile, and S-band	82.9 dB
5.0 GHz	802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, and C-band (4 GHz to 8 GHz)	114 dB



9.3.2 Phase-Reversal Protection

The OPA168x family has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the OPA168x prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. This performance is shown in Figure 45.

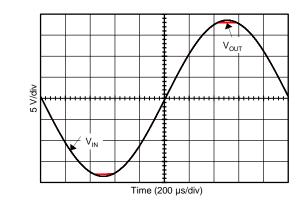
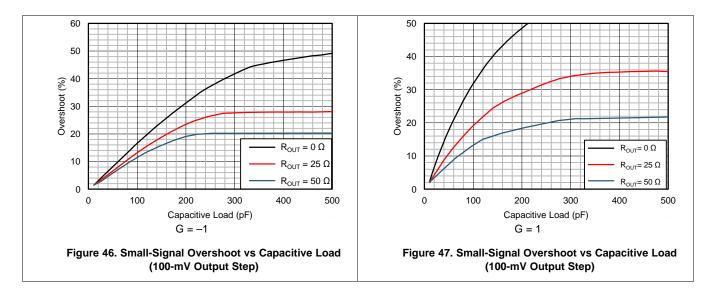


Figure 45. No Phase Reversal

9.3.3 Capacitive Load and Stability

The dynamic characteristics of the OPA168x are optimized for commonly-used operating conditions. The combination of low closed-loop gain and high capacitive loads decreases the phase margin of the amplifier and may lead to gain peaking or oscillations. As a result, heavier capacitive loads must be isolated from the output. The simplest way to achieve this isolation is to add a small resistor (for example, $R_{OUT} = 50 \Omega$) in series with the output. Figure 46 and Figure 47 show graphs of small-signal overshoot versus capacitive load for several values of R_{OUT} ; see application bulletin SBOA015 (AB-028), *Feedback Plots Define Op Amp AC Performance*, available for download from www.ti.com, for details of analysis techniques and application circuits.



9.4 Device Functional Modes

9.4.1 Common-Mode Voltage Range

The input common-mode voltage range of the OPA168x series extends 100 mV below the negative rail and within 2 V of the top rail for normal operation.

This device can operate with full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail. The typical performance in this range is summarized in Table 3.

PARAMETER	MIN	TYP	MAX	UNIT						
Input common-mode voltage	(V+) − 2		(V+) + 0.1	V						
Offset voltage		5		mV						
Offset voltage vs temperature ($T_A = -40^{\circ}C$ to $85^{\circ}C$)		10		µV/°C						
Common-mode rejection		70		dB						
Open-loop gain		60		dB						
Gain bandwidth product (GBP)		4		MHz						
Slew rate		4		V/µs						
Noise at f = 1 kHz		22		nV/√Hz						

Table 3. Typical Performance Range ($V_s = \pm 18 V$)

9.4.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

A good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. Figure 48 illustrates the ESD circuits contained in the OPA168x (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.



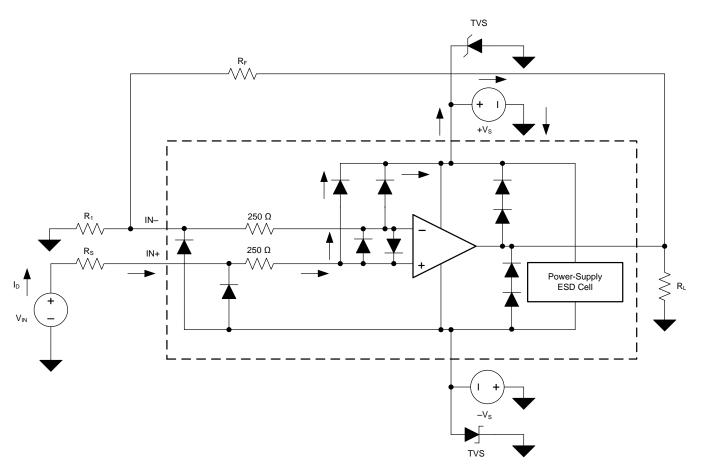


Figure 48. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event produces a short-duration, high-voltage pulse that is transformed into a short-duration, highcurrent pulse when discharging through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more amplifier device pins, current flows through one or more steering diodes. Depending on the path that the current takes, the absorption device can activate. The absorption device has a trigger, or threshold voltage, that is above the normal operating voltage of the OPA168x but below the device breakdown voltage level. When this threshold is exceeded, the absorption device quickly activates and clamps the voltage across the supply rails to a safe level.

When the operational amplifier connects into a circuit (Figure 48), the ESD protection components are intended to remain inactive and do not become involved in the application circuit operation. However, circumstances may arise where an applied voltage exceeds the operating voltage range of a given pin. If this condition occurs, there is a risk that some internal ESD protection circuits can turn on and conduct current. Any such current flow occurs through steering-diode paths and rarely involves the absorption device.

Figure 48 shows a specific example where the input voltage (V_{IN}) exceeds the positive supply voltage (+ V_S) by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If + V_S can sink the current, one of the upper input steering diodes conducts and directs current to + V_S . Excessively high current levels can flow with increasingly higher V_{IN} . As a result, the data sheet specifications recommend that applications limit the input current to 10 mA.

If the supply is not capable of sinking the current, V_{IN} can begin sourcing current to the operational amplifier and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings.



Another common question involves what happens to the amplifier if an input signal is applied to the input when the power supplies ($+V_S$ or $-V_S$) are at 0 V. Again, this question depends on the supply characteristic when at 0 V, or at a level below the input-signal amplitude. If the supplies appear as high impedance, then the input source supplies the operational amplifier current through the current-steering diodes. This state is not a normal bias condition; most likely, the amplifier will not operate normally. If the supplies are low impedance, then the current through the steering diodes can become quite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is any uncertainty about the ability of the supply to absorb this current, add external zener diodes to the supply pins; see Figure 48. Select the zener voltage so that the diode does not turn on during normal operation. However, the zener voltage must be low enough so that the zener diode conducts if the supply pin begins to rise above the safe-operating, supply-voltage level.

The OPA168x input pins are protected from excessive differential voltage with back-to-back diodes; see Figure 48. In most circuit applications, the input protection circuitry has no effect. However, in low-gain or G = 1 circuits, fast-ramping input signals can forward-bias these diodes because the output of the amplifier cannot respond rapidly enough to the input ramp. If the input signal is fast enough to create this forward-bias condition, limit the input signal current to 10 mA or less. If the input signal current is not inherently limited, an input series resistor can be used to limit the input signal current. This input series resistor degrades the low-noise performance of the OPA168x. Figure 48 illustrates an example configuration that implements a current-limiting feedback resistor.

9.4.3 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from the saturated state to the linear state. The output devices of the op amp enter the saturation region when the output voltage exceeds the rated operating voltage, either resulting from the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices need time to return back to the normal state. After the charge carriers return back to the equilibrium state, the device begins to slew at the normal slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPA168x is approximately 200 ns.

10 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The OPA168x family of amplifiers is specified for operation from 4.5 V to 36 V (\pm 2.25 V to \pm 18 V). Many of the specifications apply from –40°C to 85°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

10.2 Typical Application

This application example highlights only a few of the circuits where the OPA168x can be used.

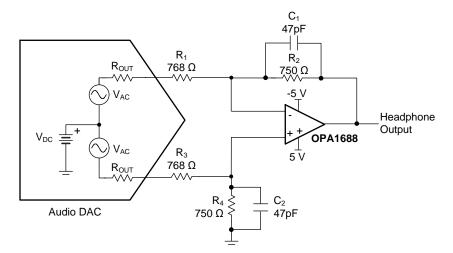


Figure 49. Headphone Amplifier Circuit Configuration for Audio DACs that Output a Differential Voltage (Single Channel Shown)

10.2.1 Design Requirements

The design requirements are:

- Supply voltage: 10 V (±5 V)
- Headphone loads: 16 Ω to 600 Ω
- THD+N: > 100 dB (1-kHz fundamental, 1 V_{RMS} in 32 Ω, 22.4-kHz measurement bandwidth)
- Output power (before clipping): 50 mW into 32 Ω



Typical Application (continued)

10.2.2 Detailed Design Procedure

amplifiers in portable devices. A common headphone amplifier circuit for audio digital-to-analog converters (DACs) with differential voltage outputs is illustrated in Figure 49. This circuit converts the differential voltage output of the DAC to a single-ended, ground-referenced signal and provides the additional current necessary for low-impedance headphones. For $R_2 = R_4$ and $R_1 = R_3$, the output voltage of the circuit is given by Equation 1:

$$V_{OUT} = 2 \times V_{AC} \frac{R_2}{R_1 + R_{OUT}}$$

where

- R_{OUT} is the output impedance of the DAC and
- $2 \times V_{AC}$ is the unloaded differential output voltage

The output voltage required for headphones depends on the headphone impedance as well as the headphone efficiency. Both values can be provided by the headphone manufacturer, with headphone efficiency usually given as a sound pressure level (SPL) produced with 1 mW of input power and denoted by the Greek letter n. The SPL at other input power levels can be calculated from the efficiency specification using Equation 2:

SPL (dB) =
$$\eta$$
 +10 log $\left(\frac{P_{IN}}{1 \text{ mW}}\right)$

Note that at extremely high power levels, the accuracy of this calculation decreases as a result of secondary effects in the headphone drivers. Figure 50 allows the SPL produced by a pair of headphones of a known sensitivity to be estimated for a given input power.

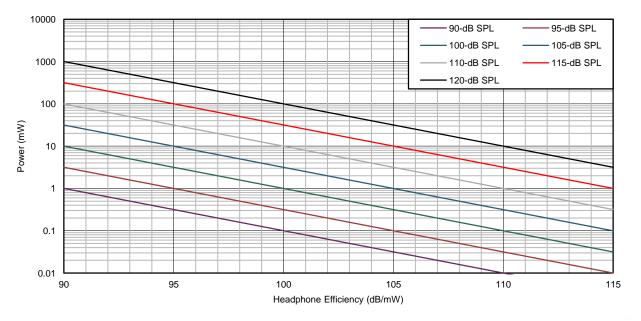


Figure 50. SPLs Produced for Various Headphone Efficiencies and Input Power Levels

OPA1688, OPA1689 SBOS724 - SEPTEMBER 2015

(1)

Typical Application (continued)

For example, a pair of headphones with a 95-dB/mW sensitivity given a 3-mW input signal produces a 100-dB SPL. If these headphones have a nominal impedance of 32 Ω , then the voltage and current from the headphone amplifier is as described in Equation 3 and Equation 4, respectively:

$$V = \sqrt{P_{IN} \times R_{HP}} = \sqrt{3 \text{ mW} \times 32 \Omega} = 310 \text{ mV}_{RMS}$$
$$I = \sqrt{\frac{P_{IN}}{R_{HP}}} = \sqrt{\frac{3 \text{ mW}}{32 \Omega}} = 9.68 \text{ mA}_{RMS}$$

(4)

(3)

Headphones can present a capacitive load at high frequencies that can destabilize the headphone amplifier circuit. Many headphone amplifiers use a resistor in series with the output to maintain stability; however this solution also compromises audio quality. The OPA168x family is able to maintain stability into large capacitive loads; therefore, a series output resistor is not necessary in the headphone amplifier circuit. TINA-TI[™] simulations illustrate that the circuit in Figure 49 has a phase margin of approximately 50 degrees with a 400-pF load connected directly to the amplifier output.

10.2.3 Application Curves

The headphone amplifier circuit in Figure 49 is tested with three common headphone impedances: 16 Ω , 32 Ω , and 600 Ω . The total harmonic distortion and noise (THD+N) for increasing output voltages is given in Figure 51. This measurement is performed with a 1-kHz input signal and a measurement bandwidth of 22.4 kHz. The maximum output power and THD+N before clipping are given in Table 4. The maximum output power into low-impedance headphones is limited by the output current capabilities of the amplifier. For high-impedance headphones (600 Ω), the output voltage capabilities of the amplifier are the limiting factor. The circuit in Figure 49 is tested using ±5-V supplies that are common in many portable systems. However, using higher supply voltages increases the output power into 600- Ω headphones.

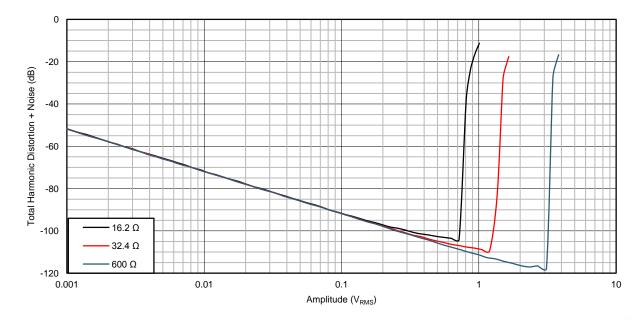


Figure 51. THD+N for Increasing Output Voltages Into Three Load Impedances (Input Signal = 1 kHz, Measurement Bandwidth = 22.4 kHz)

Typical Application (continued)

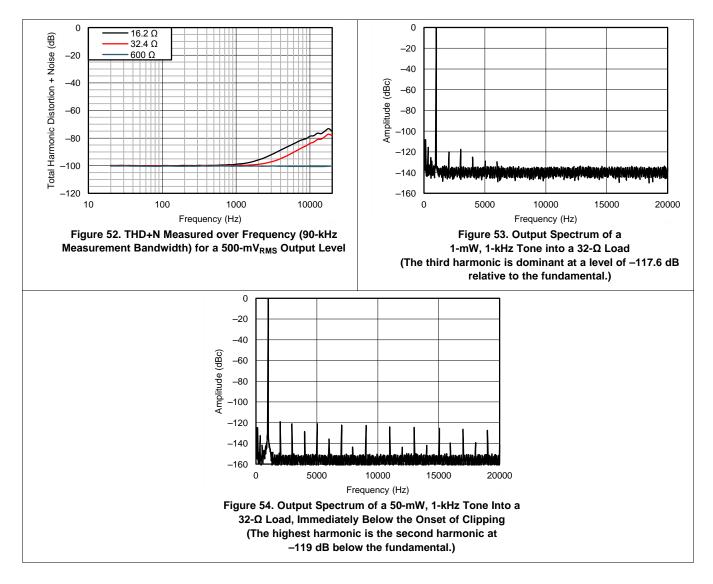
· · · · · · · · · · · · · · · · · · ·										
LOAD IMPEDANCE (Ω)	MAXIMUM OUTPUT POWER BEFORE CLIPPING (mW)	THD+N AT MAXIMUM OUTPUT POWER (dB)								
16	32	-104.1								
32	50	-109.5								
600	16	-117.8								

Table 4. Maximum Output Power and THD+N Before Clipping for Different Load Impedances

Figure 52, Figure 53, and Figure 54 further illustrate the exceptional performance of the OPA1688 as a headphone amplifier.

Figure 52 shows the THD+N over frequency for a 500-mV_{RMS} output signal into the same three load impedances previously tested.

Figure 53 and Figure 54 show the output spectrum of the OPA1688 at low (1 mW) and high (50 mW) output power levels into a $32-\Omega$ load. The distortion harmonics in both cases are approximately 120 dB below the fundamental.





11 Power Supply Recommendations

The OPA168x is specified for operation from 4.5 V to 36 V (± 2.25 V to ± 18 V); many specifications apply from -40° C to 85°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute Maximum Ratings*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or highimpedance power supplies. For more detailed information on bypass capacitor placement, see the *Layout* section.

12 Layout

12.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see SLOA089, *Circuit Board Layout Techniques*.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in Figure 55, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.



12.2 Layout Example

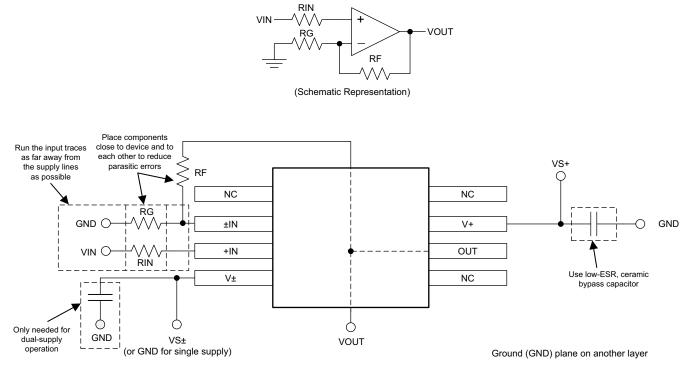


Figure 55. Operational Amplifier Board Layout for a Noninverting Configuration

TEXAS INSTRUMENTS

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13 Device and Documentation Support

13.1 Device Support

13.1.1 Development Support

13.1.1.1 TINA-TI™ (Free Software Download)

TINA[™] is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

NOTE

These files require that either the TINA software (from DesignSoft[™]) or TINA-TI software be installed. Download the free TINA-TI software from the TINA-TI folder.

13.2 Documentation Support

13.2.1 Related Documentation

SBOA015 (AB-028) — Feedback Plots Define Op Amp AC Performance

SBOA128 — EMI Rejection Ratio of Operational Amplifiers

SLOA089 — Circuit Board Layout Techniques

SLOD006 — Op Amps for Everyone

TIPD128 — Capacitive Load Drive Solution using an Isolation Resistor

13.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
OPA1688	Click here	Click here	Click here	Click here	Click here
OPA1689	Click here	Click here	Click here	Click here	Click here

Table 5. Related Links

13.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.



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SoundPlus is a trademark of Texas Instruments, Inc.

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Blu-Ray is a trademark of Blu-ray Disc Association (BDA).

Bluetooth is a registered trademark of Bluetooth SIG, Inc.

TINA, DesignSoft are trademarks of DesignSoft, Inc.

All other trademarks are the property of their respective owners.

13.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
OPA1688ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	O1688A	Samples
OPA1688IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	O1688A	Samples
OPA1688IDRGR	ACTIVE	SON	DRG	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OP1688	Samples
OPA1688IDRGT	ACTIVE	SON	DRG	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OP1688	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



18-Sep-2015

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA1688IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA1688IDRGR	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA1688IDRGT	SON	DRG	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

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PACKAGE MATERIALS INFORMATION

7-Dec-2015



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA1688IDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA1688IDRGR	SON	DRG	8	3000	367.0	367.0	35.0
OPA1688IDRGT	SON	DRG	8	250	210.0	185.0	35.0

MECHANICAL DATA



E. JEDEC MO-229 package registration pending.



DRG (S-PWSON-N8)

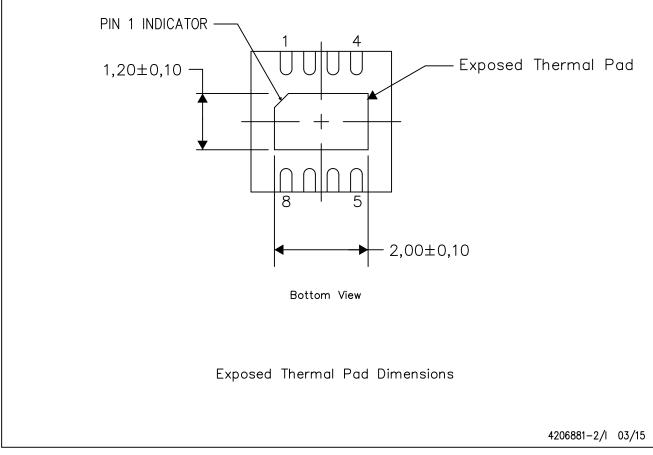
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

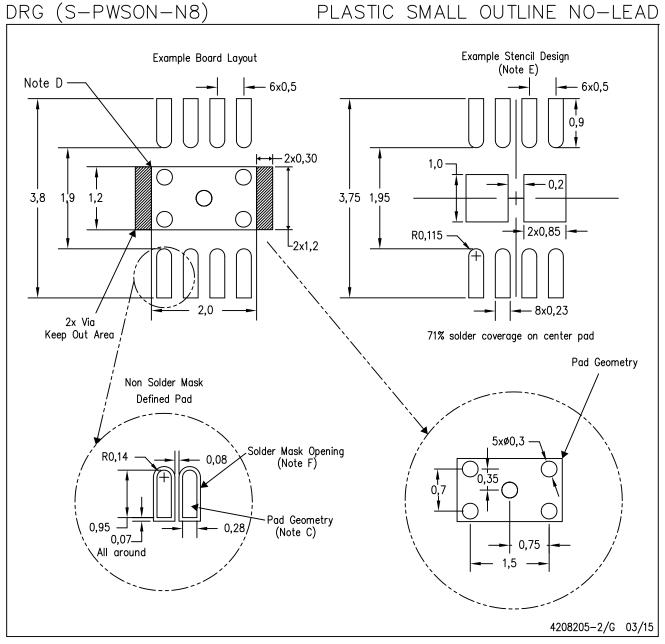
For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.









NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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